NSN 5961-00-245-6732

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Inclosure Material:

Metal

Overall Length:

0.230 inches

Terminal Length:

1.500 inches

Overall Diameter:

0.370 inches

Internal Configuration:

Junction contact

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-5

Internal Junction Configuration:

Npn

Mounting Method:

Terminal

Terminal Circle Diameter:

0.100 inches

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

100.0 breakdown voltage, collector-to-base, emitter open and 8.0 emitter to base voltage, static, collector open and 100.0 breakdown

voltage, collector-to-emitter, base open

Current Rating Per Characteristic:

500.00 milliamperes collector current, dc and 250.00 milliamperes base current, dc

Power Rating Per Characteristic:

1.0 watts total device dissipation

Transfer Ratio:

90.0 static forward current transfer ratio, common-emitter

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

Terminal Type And Quantity:

3 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

A110a0